



74HC594

8-BIT SHIFT REGISTER WITH 8-BIT OUTPUT REGISTER

Description

The 74HC594 is a high speed CMOS device.

An eight bit shift register accepts data from the serial input (DS) on each positive transition of the shift register clock (SHCP). When asserted low, the shift regisister reset function (SHR) sets all shift register values to zero and is independent of all clocks. Also when asserted low, the storage register reset function (STR) sets all shift register values to zero and is independent of all clocks.

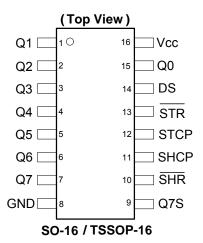
Data from the input serial shift register is placed in the output register with a rising pulse on the storages resister clock (STCP). storage resister includes output Q7S which is used for cascading information between devices. As the information moves into the storage register, it is asserted on the push-pull outputs Q0-Q7.

All registers capture data on rising edge and change output on the falling edge. If both clocks are connected together, the input shift register is always one clock cycle ahead of the output register.

Features

- Wide Supply Voltage Range from 2.0V to 6.0V
- Sinks or sources 8mA at V_{CC}= 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- Inputs accept up to 6.0V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Serial to Parallel Data conversion
- Capture and hold data for extended periods of time.
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed.
- Wide array of products such as:
 - Computer Peripherals
 - **Appliances**
 - Industrial Control

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click here for ordering information, located at the end of datasheet

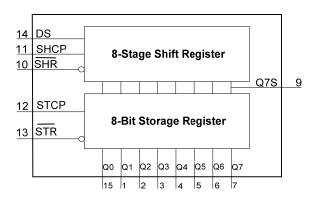
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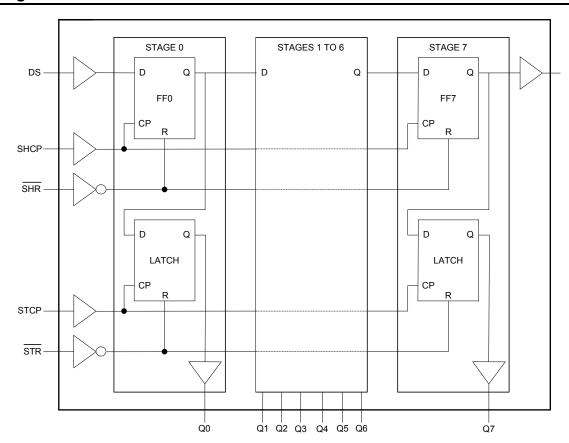
Pin Descriptions

Pin Number	Pin Name	Description
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	SHR	Shift Register Reset active low
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	STR	Storage Register Reset active low
14	DS	Serial Data input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

Functional Diagram



Logic Diagram



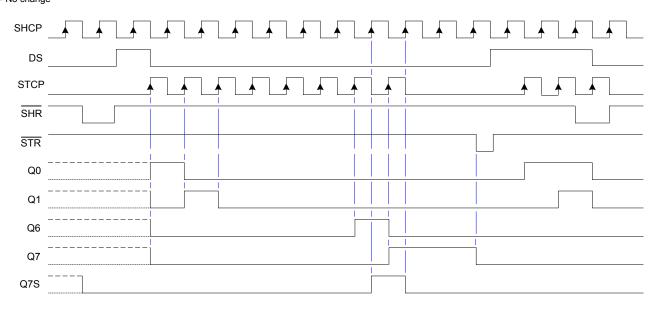
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Functional Description and Timing Diagram

	Control			Input	Output		Forestina
SHR	STR	SHCP	STCP	DS	Q7S	Qn	Function
L	Х	Х	Х	Х	L	NC	Clear Shift Register
Х	L	Х	Х	Х	NC	L	Clear Storage Register
Н	Х	1	L	H or L	Q6S	NC	Loads DS into shift register stage 0. All Q _S shifted
Н	Н	Х	1	Х	NC	Qs	Contents of shift register moved to starge register all Qs -> QN
Н	Н	1	1	H or L	Q6S	QnS	Shift Register one pulse count ahead of storage register.

H=HIGH voltage state L=LOW voltage state ↑=LOW to HIGH transition X= don't care – high or low (not floating) NC= No change



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Desc	Rating	Unit		
ESD HBM	Human Body Model ESD Protection	2	KV		
ESD CDM	Charged Device Model ESD Protect	etion	1	KV	
ESD MM	Machine Model ESD Protection		200	V	
V _{CC}	Supply Voltage Range		-0.5 to +7.0	V	
VI	Input Voltage Range		-0.5 to +7.0	V	
Vo	Voltage applied to output in high or	r low state	-0.3 to V _{CC} +0.5	V	
l _{IK}	Input Clamp Current V _I < -0.5V	Input Clamp Current V _I < -0.5V			
I _{IK}	Input Clamp Current VI > Vcc +().5V	20	mA	
I _{OK}	Output Clamp Current V _O <-0.5V		-20	mA	
Іок	Output Clamp Current Vo > Vcc	+ 0.5V	20	mA	
	Continuous autout aurrent	Q7 standard output	±25	mA	
Io	Continuous output current	Qn bus driver outputs	±35	mA	
Icc	Continuous current through Vcc		70	mA	
I _{GND}	Continuous current through GND	Continuous current through GND			
TJ	Operating Junction Temperature	-40 to +150	°C		
T _{STG}	Storage Temperature	-65 to +150	°C		
P _{TOT}	Total Power Dissipation		500	mW	

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

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Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage	_	2.0	6.0	V
VI	Input Voltage	_	0	Vcc	V
Vo	Output Voltage	_	0	Vcc	V
		V _{CC} = 2.0V	-	1000	0.4
$\Delta t/\Delta V$	Input transition rise or fall rate	V _{CC} = 4.5V	-	500	ns/V
		V _{CC} = 6.0V	-	400	_
T _A	Operating free-air temperature	-	-40	+125	°C

Note:

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V	Т	A = +25°	С	T _A = -40°C	C to +85°C	T _A = -40°C	to +125°C	Unit		
Syllibol	Farameter	rest Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Onit		
		-	2.0V	1.5	1.2	_	1.5	-	1.5	-			
V_{IH}	High-level Input Voltage	-	4.5V	3.15	2.4	_	3.15	_	3.15	_	V		
	input voltage	-	6.0V	4.2	3.2	_	4.2	-	4.2	_			
		-	2.0V	-	8.0	0.5	-	0.5	-	0.5			
V_{IL}	Low-level input voltage	-	4.5V	-	2.1	1.35	-	1.35	-	1.35	V		
	Input voltage	-	6.0V	-	2.8	1.8	-	1.8	-	1.8			
	High Level		2.0V	1.9	2.0	_	1.9	_	1.9	-			
	Output	I _{OH} = -20μA All outputs	4.5V	4.4	4.5	_	4.4	-	4.4	_			
	Voltage	All outputs	6.0V	5.9	6.0	_	5.9	_	5.9	_			
V_{OH}	070	I _{OH} = -4mA	4.5V	3.98	4.32	=	3.84	=	3.7	=	V		
	Q7S output	I _{OH} = -5.2mA	6.0V	5.48	5.81	-	5.34	-	5.2	-			
	Qn Bus	I _{OH} = -6.0mA	4.5V	3.98	4.32	_	3.84	_	3.7	_			
	Outputs	I _{OH} = -7.8mA	6.0V	5.48	5.81	_	5.34	=	5.2	=			
	Low-level Output Voltage	Output	Output		2.0V	-	0	0.1	=	0.1	=	0.1	
				Output $I_{OL} = 20\mu A$	4.5V	=	0	0.1	=	0.1	=	0.1	
			All outputs	6.0V	_	0	0.1	_	0.1	_	0.1		
V_{OL}	070	I _{OL} = 4.0mA	4.5V	_	.15	0.26	-	0.33	-	0.4	V		
	Q7S output	I _{OL} = 5.2mA	6.0V	=	.16	0.26	=	0.33	=	0.4			
	Qn Bus	I _{OL} = 6.0mA	4.5V	-	.15	0.26	_	0.33	-	0.4			
	Outputs	I _{OL} = 7.8mA	6.0V	_	.16	0.26	-	0.33	-	0.4			
II	Input Current	V_I = GND to 5.5V	6.0V	-	_	±0.1	_	± 1	-	± 1	μA		
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O = 0$	6.0V	-	-	8.0	-	80		160	μА		
Ci	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	6.0V	-	3.5	10	-	10	_	10	pF		

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V _{CC} = 5V Typ	Unit
C_{pd}	Power dissipation capacitance	f = 1 MHz all outputs switching-no load	51	pF

^{5.} Unused inputs should be held at V_{CC} or Ground.

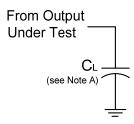


Switching Characteristics

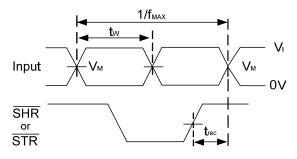
Symbol /	D:	T10 !!!!	.,	-	Γ _A = +25°	<u> </u>	-40°C t	o +85°C	-40°C to	+125°C	Unit																
Parameter	Pins	Test Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max																	
			2.0V	6	30	-	4.8	-	4	-																	
f_{MAX}	SHCP or	Figure 2	4.5V	30	92	_	24	_	20	-																	
Maximum	STCP	r iguic 2	5.0V		100	_		=		_	MHz																
Frequency		-	6.0V	35	109	_	28		24	_																	
	OLIOD		2.0V	80	10	_	100	_	120	_																	
	SHCP HIGH or	Figure 2	4.5V	16	4	_	20	_	24	_																	
	LOW	1 19410 2	6.0V	14	3	_	17	_	20	_																	
	OTOD		2.0V	80	10	_	100	_	120	_																	
t _W	STCP HIGH or	Figure 2	4.5V	16	4	_	20	_	24	_																	
Pulse Width	LOW	1 iguic 2	6.0V	14	3	_	17	_	20	_	ns																
	CUD and		2.0V	80	14		100	_	120	_																	
	SHR and STR		4.5V	16	5	_	20	_	24	_																	
	HIGH or	Figure 2								_																	
	LOW		6.0V	14	4	_	17	_	20	_																	
	D 0 1		2.0V	100	10	-	125	-	150	-																	
	DS to SHCP	Figure 2	4.5V	20	4	_	25	_	30	_	ns																
	01101		6.0V	17	3	_	21	_	26	-																	
			2.0V	100	14	_	125	_	150	_																	
t _{SU}	SHR to STCP	Figure 2	4.5V	20	5	-	25	_	30	-	ns																
Set-up Time	3105		6.0V	17	4	_	21	_	26	-																	
			2.0V	100	17	-	125	_	150	-																	
	SHCP to STCP	Figure 2	4.5V	20	6	_	25	_	30	_	ns																
			6.0V	17	5	_	21	_	26	_																	
			2.0V	=	44	150	_	185	_	225																	
	SHCP to	Figure 2	4.5V	=	16	30	_	37	=	45																	
	Q7S	9	5.0V	_	13	_	_	_	_	_	ns																
t _{PD}			6.0V	_	14	26	_	31	_	38																	
Propagation	STCP to Qn		2.0V	_	44	150	_	185	_	225																	
Delay		Figure 2	4.5V	_	16	30	_	37	_	45																	
																		1 iguic 2	5.0V	_	13	_	_	_	_	_	ns
			-	6.0V	_	14	26	_	31	_	38																
			2.0V	25	-8	_	30	_	35	_																	
t _H	DS to	Figure 2	4.5V	5	-3	_	6	_	7	_	ns																
Hold Time	SHCP			-	6.0V	4	-2	_	5	_	6	_	113														
	OUD to		2.0V	50	-14	_	65	_	75																		
t _{REC}	SHR to SHCP and	Figure 2	4.5V	10	-5	_	13		15																		
Recovery Time	STR to	ga. s _		1		_		_		=	ns																
	STCP		6.0V	9	-4	-	11	_	13	-																	
			2.0V	_	39	150	-	185	-	225																	
	SHR to	Figure 2	4.5V	_	14	30	_	37	_	45	no																
	Q7S	Figure 2	5.0V	_	11	_	-	_	_	_	ns																
t _{PHL}						6.0V	=	12	26	=	31	=	38														
Propagation Delay			2.0V	_	39	125	-	155	=	185																	
Delay			4.5V	_	14	25	_	31	_	37																	
	STR to Qn	Figure 2	5.0V	_	11	_	_	_	_	-	ns																
			6.0V	_	12	21	_	26	_	31																	
			2.0V	=	19	75	_	95	_	110																	
	Serial data	Figure 2	4.5V	_	7	15	_	19	_	22	ns																
t _{THL}	output Q7S]	6.0V	_	6	13	_	16	_	19																	
ransition Time	Dorollol		2.0V	_	14	60	_	75	_	90																	
	Parallel Data	Figure 2	4.5V	<u> </u>	5	12	_	15	_	18	ns																
	Outputs Q _N	1 19410 2	6.0V		4	10	_	13	_	15	113																



Parameter Measurement Information



V	Inp	outs	V		
V _{CC}	VI	t _r /t _f	V _M	CL	
2.0V	V _{CC}	6ns	V _{CC} /2	50pF	
4.5V	Vcc	6ns	V _{CC} /2	50pF	
5.0V	V _{CC}	6ns	V _{CC} /2	15pF	
6.0V	V _{CC}	6ns	V _{CC} /2	50pF	



Timing Input I OV

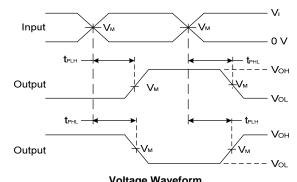
tsu VM

Data Input VM

OV

Voltage Waveform Pulse Duration and Recovery Time

Voltage Waveform Set-up and Hold Times



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

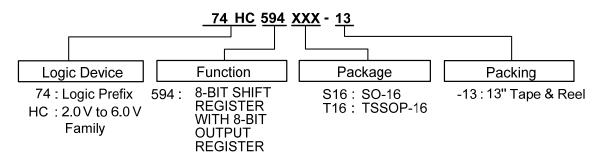
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD}.

Figure 2 Load Circuit and Voltage Waveforms



Ordering Information

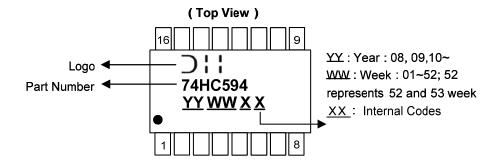


Part Number	Dookses Code	Dookoaina	7" Tape and	Reel (Note 6)
Part Number	Package Code Packaging		Quantity	Part Number Suffix
74HC594S16-13	S16	SO-16	2500/Tape & Reel	-13
74HC594T16-13	T16	TSSOP-16	2500/Tape & Reel	-13

Note: 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-16, TSSOP16



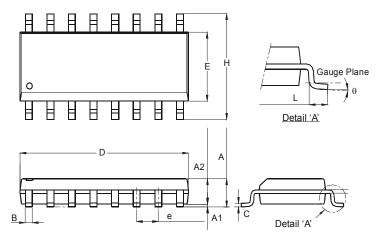
Part Number	Package
74HC594S16	SO-16
74HC594T16	TSSOP-16



Package Outline Dimensions (All dimensions in mm.)

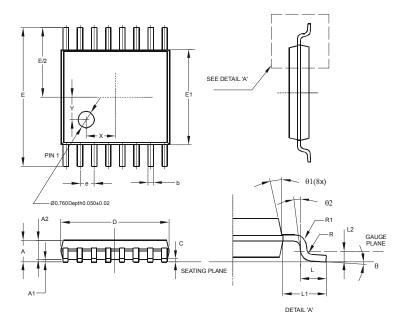
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-16



	SO-16	
Dim	Min	Max
Α	1.40	1.75
A1	0.10	0.25
A2	1.30	1.50
В	0.33	0.51
U	0.19	0.25
D	9.80	10.00
Е	3.80	4.00
е	1.27	Тур
Η	5.80	6.20
١	0.38	1.27
Θ	0°	8°
All D	imension	s in mm

Package Type: TSSOP-16



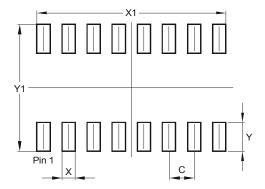
TSSOP-16							
Dim	Min Max Typ						
Α	-	1.08	-				
A1	0.05	0.15	-				
A2	0.80	0.93	-				
b	0.19	0.30	-				
С	0.09	0.20	-				
D	4.90	5.10	-				
Е	6	.40 BS	SC SC				
E1	4.30	4.50	-				
е	0	.65 BS	SC SC				
L	0.45	0.75	-				
L1	1	.00 R	EF				
L2	0	.25 BS	SC SC				
R	0.09	ı	1				
R1	0.09	ı	ı				
X	ı	ı	1.350				
Υ	ı	ı	1.050				
Θ	0°	8°	-				
Θ1	5°	15°	-				
Θ2	0°	-	-				
All E	Dimen	sions	in mm				



Suggested Pad Layout

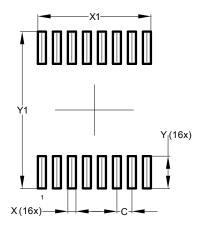
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)
С	1.270
Х	0.670
X1	9.560
Y	1.450
Y1	6.400

Package Type: TSSOP-16



Dimensions	Value (in mm)
С	0.650
Х	0.350
X1	4.900
Y	1.400
Y1	6.800



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